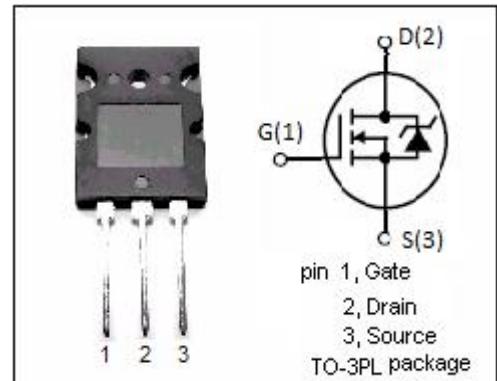


isc N-Channel MOSFET Transistor

IRFIP054

• FEATURES

- With TO-3PL packaging
- Low switching loss
- Ultra low gate charge
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz



• APPLICATIONS

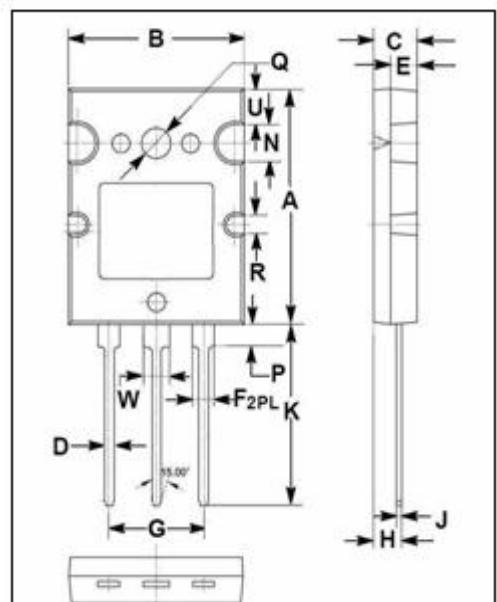
- Switching applications
- DC-DC converters
- Uninterruptible power supply

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	60	V
V_{GSS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	75	A
I_{DM}	Drain Current-Single Pulsed	225	A
P_D	Total Dissipation	70	W
T_j	Operating Junction Temperature	-55~150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	1.79	$^\circ\text{C}/\text{W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ\text{C}/\text{W}$



DIM	mm	
	MIN	MAX
A	25.50	26.50
B	19.80	20.20
C	4.50	5.50
D	0.90	1.10
E	2.80	3.20
F	2.40	2.60
G	10.80	11.00
H	3.10	3.30
J	0.50	0.70
K	20.00	21.00
N	3.90	4.50
P	2.40	2.60
Q	3.10	3.50
R	1.90	2.60
U	3.90	4.10
W	2.90	3.25

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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D= 0.25\text{mA}$	60			V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\pm 20\text{V}; \text{I}_D=0.25\text{mA}$	2.0		4.0	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D=38\text{A}$			14	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			± 0.1	$\mu\text{ A}$
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 60\text{V}; \text{V}_{\text{GS}}= 0\text{V}$			1	$\mu\text{ A}$
V_{SDF}	Diode forward voltage	$\text{I}_{\text{SD}}=38\text{A}, \text{V}_{\text{GS}} = 0 \text{ V}$			1.5	V

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